Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC5720

MEDIUM POWER AMPLIFIER APPLICATIONS STOROBO FLASH APPLICATIONS

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-Base voltage		V _{CBO}	15	V	
Collector-Emitter voltage		V_{CEO}	10	V	
Emitter-Base voltage		V _{EBO}	7	V	
Collector current	DC	Ic	5	А	
	Pulsed	I _{CP}	9		
Collector power dissipation		P _C (Note1)	550	mW	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note1: When a device is mounted on a glass epoxy board (35 mm \times 30 mm \times 1mm)

Electrical Characteristics (Ta = 25°C)

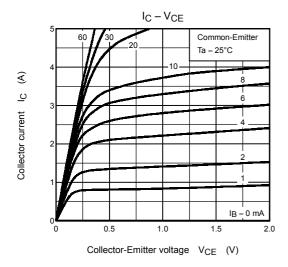
4.2 MAX .						
0.55 MAX.						
3. BASE						
JEDEC —						
JEITA —						
TOSHIBA 2-4E1	IA					
Weight: 0.12 g (typ.)	-					

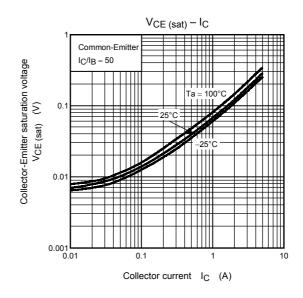
Weight: 0.13 g (typ.)

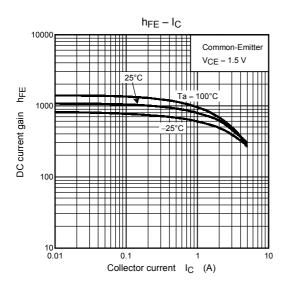
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 15 V, I _E = 0	_	_	0.1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	0.1	μА
Collector-Emitter breakdown voltage	V _{(BR)CEO}	I _C = 1 mA, I _B = 0	10	_	_	V
DC current gain	h _{FE(1)} (Note2)	$V_{CE} = 1.5 \text{ V}, I_{C} = 0.5 \text{ A}$	700		2000	
	h _{FE(2)} (Note2)	V _{CE} = 1.5 V, I _C = 2 A	450	_	_	
	h _{FE(3)} (Note2)	V _{CE} = 1.5 V, I _C = 5 A	240	_	_	
Collector-Emitter saturation voltage	V _{CE (sat)} (Note2)	I _C = 3 A, I _B = 60 mA		_	0.25	٧
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	30	_	pF

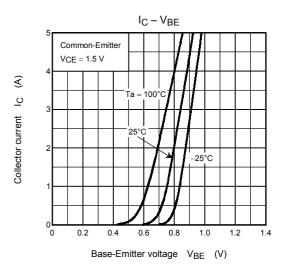
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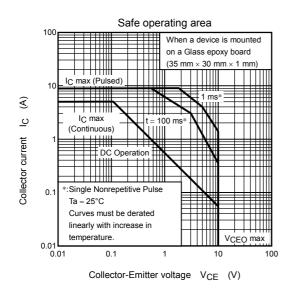
Note2: Pulse test

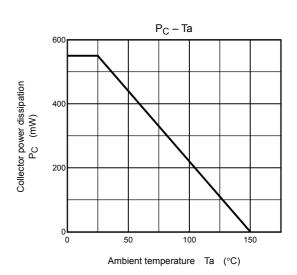












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